

23A005

23A005 Information

Heisener.com	Part Number Manufacturer Category Description Package	23A005 Microsemi Corporation Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF TRANS RF BIPO 3W 400MA 55BT2 55BT For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

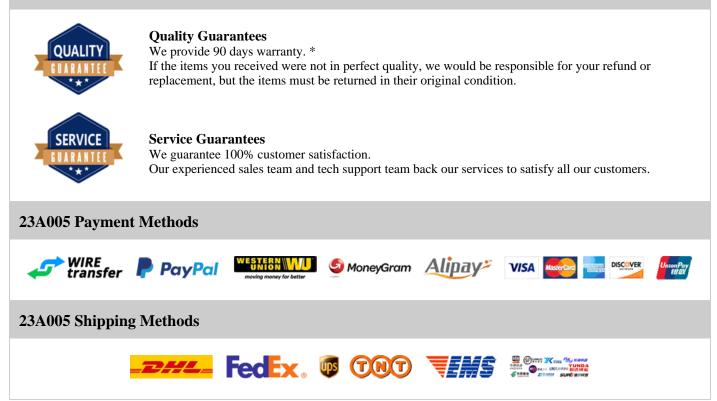
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



23A005 Specifications

Manufacturer Part Number	23A005	
Manufacturer	Microsemi Corporation	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - RF	
Package	55BT	
Series	-	
Transistor Type	NPN	
Voltage - Collector Emitter Breakdown (Max)	22V	
Frequency - Transition	4.3GHz	
Noise Figure (dB Typ @ f)	-	
Gain	8.5dB ~ 9.5dB	
Power - Max	3W	
DC Current Gain (hFE) (Min) @ Ic, Vce	20 @ 100mA, 5V	
Current - Collector (Ic) (Max)	400mA	
Operating Temperature	200°C (TJ)	
Mounting Type	Chassis Mount	
Package / Case	55BT	
Supplier Device Package	55BT	
	Report errors?	

23A005 Guarantees



If you have any question about 23A005, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com